NSN 5961-00-004-5911

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-004-5911 **Inclosure Material:** Metal **Overall Length:** 0.265 inches **Overall Height:** 0.065 inches **Overall Width:** 0.260 inches **Component Name And Quantity:** 4 transistor **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor **Voltage Rating In Volts Per Characteristic:** 60.0 collector to base voltage, dc all transistor and 60.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 300.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No